VS-10ETF0...-M3 Series

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	10 A					
V _R	200 V, 400 V, 600 V					
V _F at I _F	1.2 V					
I _{FSM}	130 A					
t _{rr}	50 ns					
T _J max.	150 °C					
Snap factor	0.6					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max operating junction temperature
- · Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF0... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES					
V _{RRM}		200 to 600	V				
I _{F(AV)}	Sinusoidal waveform	10	٨				
I _{FSM}		130	— A				
t _{rr}	1 A, 100 A/µs	50	ns				
V _F	10 A, T _J = 25 °C	1.2	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-10ETF02-M3	200	300					
VS-10ETF04-M3	400	500	3				
VS-10ETF06-M3	600	700					

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_C = 128 °C, 180° conduction half sine wave	10			
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V_{RRM} applied	110	A		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	130			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	60	A ² s		
Maximum - tior rusing		10 ms sine pulse, no voltage reapplied	85	A-2		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	850	A²√s		

Revision: 29-Nov-2021

Document Number: 96210



HALOGEN

FREE



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.2	V	
Forward slope resistance	r _t	T.I = 150 °C		23.5	mΩ	
Threshold voltage	V _{F(TO)}	1J = 150 C		0.85	V	
Maximum reverse leakage current	1	T _J = 25 °C	V - Roted V	0.1	mA	
Maximum reverse leakage current	IRM	T _J = 150 °C	$V_R = Rated V_{RRM}$	3.0	ШA	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	In at 10 Ani	200	ns			
Reverse recovery current	I _{rr}	. I _F at 10 A _{pk} 25 A/µs	2.75	А			
Reverse recovery charge	Q _{rr}	25 °C	0.32	μC			
Snap factor	S		0.6		I V I _{RM(REC)}		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and si temperature range	torage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistation to case	ance	R _{thJC}	DC operation	1.5	
Maximum thermal resistance junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistant case to heatsink	:e,	R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style TO-220AC 2L (JEDEC)	10ETF02 10ETF04 10ETF06	



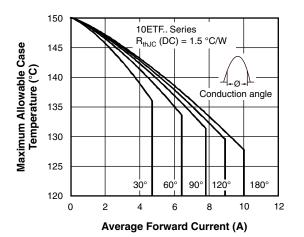


Fig. 1 - Current Rating Characteristics

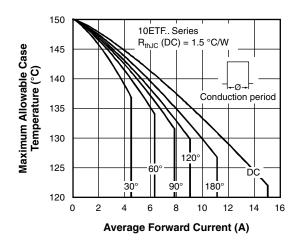


Fig. 2 - Current Rating Characteristics

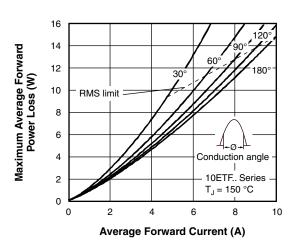


Fig. 3 - Forward Power Loss Characteristics

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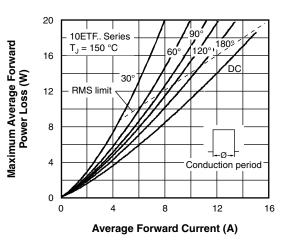


Fig. 4 - Forward Power Loss Characteristics

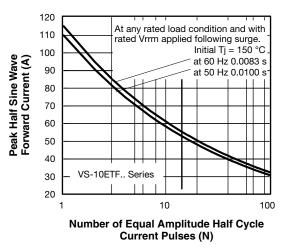


Fig. 5 - Maximum Non-Repetitive Surge Current

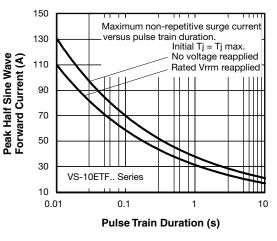


Fig. 6 - Maximum Non-Repetitive Surge Current

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Instantaneous Forward Current (A)

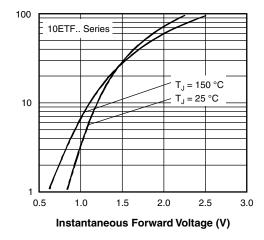


Fig. 7 - Forward Voltage Drop Characteristics

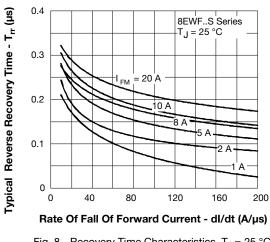


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

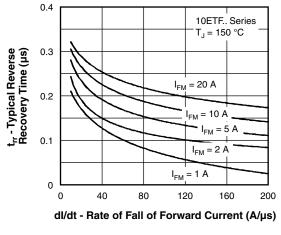


Fig. 9 - Recovery Time Characteristics, T_J = 150 $^\circ\text{C}$

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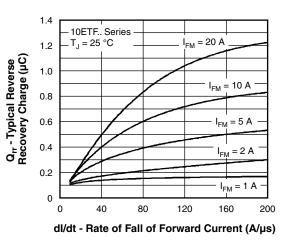


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

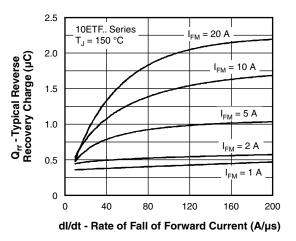


Fig. 11 - Recovery Charge Characteristics, $T_J = 150$ °C

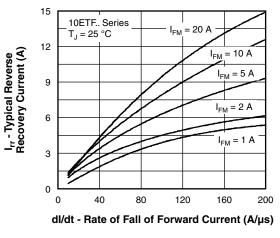


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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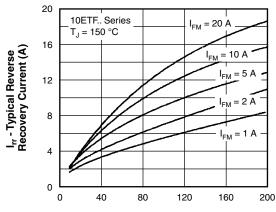
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

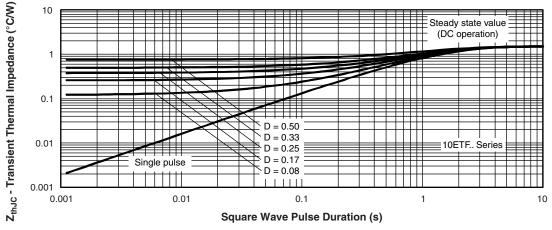
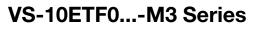


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

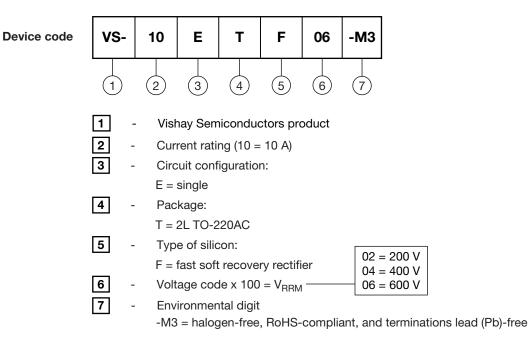


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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-10ETF02-M3	50	Antistatic plastic tube					
VS-10ETF04-M3	50	Antistatic plastic tube					
VS-10ETF06-M3	50	Antistatic plastic tube					

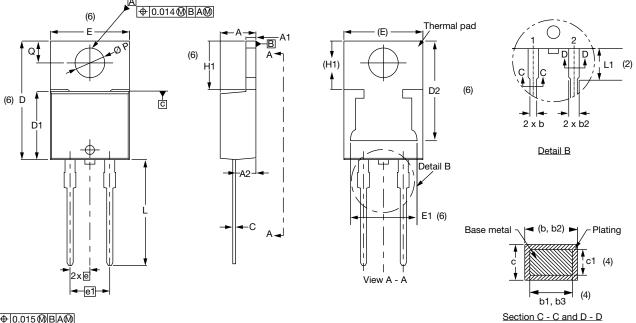
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96156</u>					
Part marking information	www.vishay.com/doc?95391				



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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC[®] outline TO-220AC

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

(4) Dimension b1, b3, and c1 apply to base metal only

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 07-Mar-2022

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 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994 $\,$

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Controlling dimensions: inches



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